# mail

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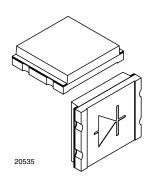


### **TEMD5020X01**



**Vishay Semiconductors** 

### Silicon PIN Photodiode, RoHS Compliant, Released for Lead (Pb)-free Reflow Soldering, AEC-Q101 Released



TEMD5020X01 is a high speed and high sensitive PIN

photodiode. It is a miniature surface mount device (SMD)

including the chip with a 4.4 mm<sup>2</sup> sensitive area detecting

### **FEATURES** Package type: surface mount

- · Package form: top view
- Dimensions (L x W x H in mm): 5 x 4.24 x 1.12
- Radiant sensitive area (in mm<sup>2</sup>): 4.4
- AEC-Q101 qualified
- High photo sensitivity
- · High radiant sensitivity
- · Suitable for visible and near infrared radiation
- · Fast response times
- Angle of half sensitivity:  $\varphi = \pm 65^{\circ}$
- Floor life: 72 h, MSL 4, acc. J-STD-020
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### Note

Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

#### **APPLICATIONS**

• High speed photo detectors

PRODUCT SUMMARY			
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ0.1 (nm)
TEMD5020X01	35	± 65	430 to 1100

#### Note

DESCRIPTION

visible and near infrared radiation.

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
TEMD5020X01	Tape and reel	MOQ: 1500 pcs, 1500 pcs/reel	Top view	

Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	60	V	
Power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	Pv	215	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 110	°C	
Soldering temperature	Acc. reflow solder profile fig. 8	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Soldered on PCB with pad dimensions: 4 mm x 4 mm	R <sub>thJA</sub>	350	K/W	

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### TEMD5020X01



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PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	VF		1	1.3	V
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	V <sub>(BR)</sub>	60			V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		2	30	nA
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	CD		48		pF
	V <sub>R</sub> = 3 V, f = 1 MHz, E = 0	C <sub>D</sub>		17	40	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of Vo	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	TK <sub>Vo</sub>		- 2.6		mV/K
Short circuit current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	l <sub>k</sub>		32		μA
Temperature coefficient of $I_k$	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	ΤK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \\ V_R = 5 \text{ V}$	I <sub>ra</sub>	25	35		μA
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		λρ		900		nm
Range of spectral bandwidth		λ 0.1		430 to 1100		nm
Noise equivalent power	$V_{\rm R} = 10 \text{ V}, \lambda = 950 \text{ nm}$	NEP		4 x 10 <sup>-14</sup>		W/√Hz
Rise time	$V_{R} = 10 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega,$ $\lambda = 820 \text{ nm}$	t <sub>r</sub>		100		ns
Fall time	$V_{R} = 10 \text{ V},  \text{R}_{L} = 1  \text{k}\Omega,$ $\lambda = 820 \text{ nm}$	t <sub>f</sub>		100		ns

**BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

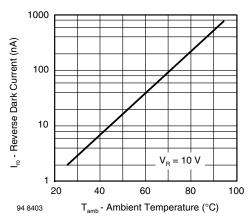


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

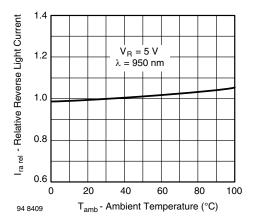


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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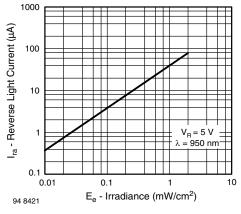


Fig. 3 - Reverse Light Current vs. Irradiance

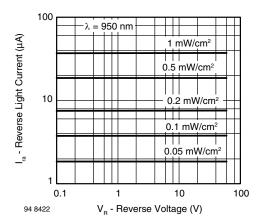


Fig. 4 - Reverse Light Current vs. Reverse Voltage

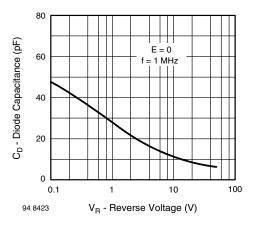


Fig. 5 - Diode Capacitance vs. Reverse Voltage

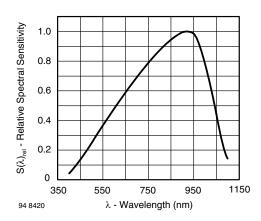


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

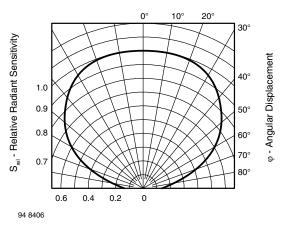


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement



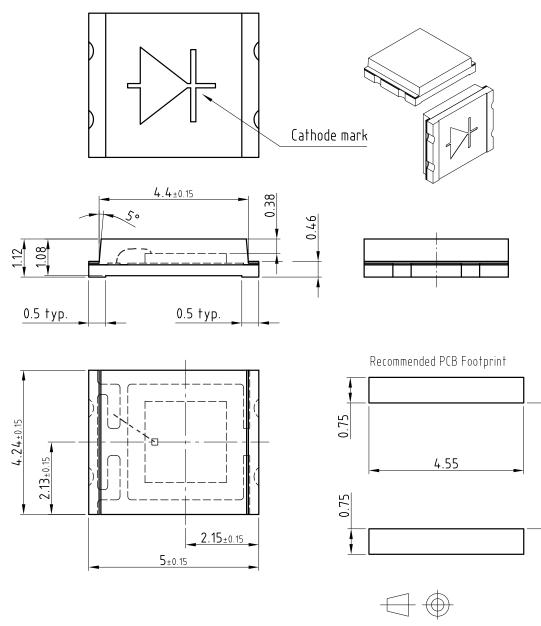


PACKAGE DIMENSIONS in millimeters

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m



technical drawings according to DIN specifications

Drawing-No.: 6.541-5059.01-4 Issue: 4; 26.04.07 19280

Not indicated tolerances  $\pm 0.1$ 

Rev. 1.7, 23-Aug-11

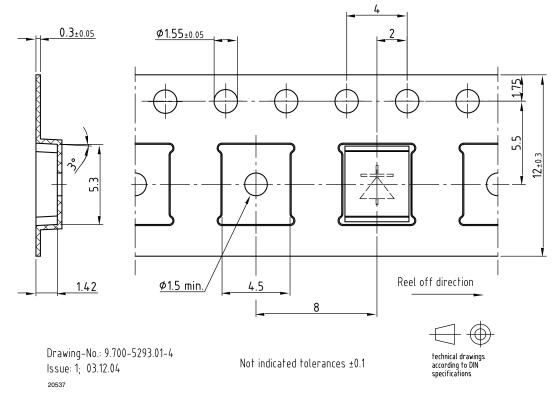
4
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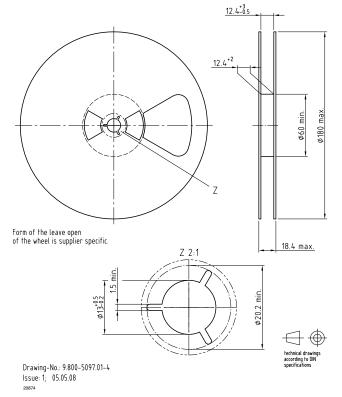


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#### TAPING DIMENSIONS in millimeters



### **REEL DIMENSIONS** in millimeters





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### SOLDER PROFILE

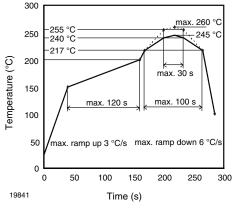


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

#### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020: Moisture sensitivity: level 4 Floor life: 72 h Conditions:  $T_{amb} < 30$  °C, RH < 60 %

#### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions: 192 h at 40 °C (+ 5 °C), RH < 5 % or 96 h at 60 °C (+ 5 °C), RH < 5 %.



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